

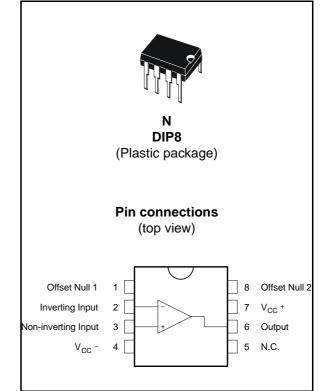
Features

- Extremely low offset: 150µV/ max.
- Low input bias current: 1.8nA
- LOW V_{io} drift: 0.5µV/°C
- Ultra stable with time: 2μ V/month max.
- Wide supply voltage range: ±3V to ± 22V
- Temperature range: 0°C to -105°C

Description

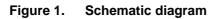
The OP07 is a very high precision op-amp with an offset voltage maximum of 150μ V.

Offering also low input current (1.8nA) and high gain (400V/mV), the OP07C is particularly suitable for instrumentation applications.





1 Schematic diagram



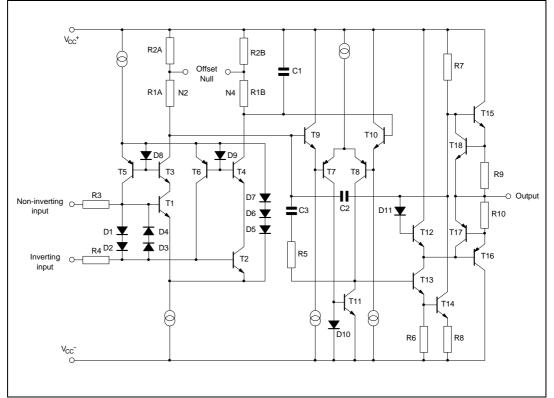
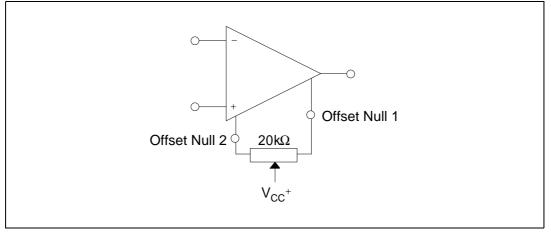


Figure 2. Input offset voltage nulling circuit





2 Absolute maximum ratings

Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|-------------------|---|------------|------|
| V _{CC} | Supply voltage | ± 22 | V |
| V _{id} | Differential input voltage | ± 30 | V |
| V _i | Input voltage | ± 22 | V |
| T _{oper} | Operating temperature | -40 to 105 | °C |
| T _{stg} | Storage temperature | -65 to 150 | °C |
| R _{thja} | Thermal resistance junction to ambient ^{(1) (2)} DIP8 | 85 | °C/W |
| R _{thjc} | Thermal resistance junction to case ^{(1) (2)} DIP8 | 41 | °C/W |
| | HBM: human body model ⁽³⁾ | 1.5 | kV |
| ESD | MM: machine model ⁽⁴⁾ | 200 | V |
| | CDM: charged device model ⁽⁵⁾ | 1.5 | kV |

1. Short-circuits can cause excessive heating and destructive dissipation.

2. R_{th} are typical values.

3. Human body model: 100pF discharged through a $1.5k\Omega$ resistor between two pins of the device, done for all couples of pin combinations with other pins floating.

 Machine model: a 200pF cap is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5Ω). Done for all couples of pin combinations with other pins floating.

5. Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.



3 **Electrical characteristics**

Symbol Parameter Min. Typ. Max. Unit Input offset voltage 150 60 V_{io} μV $0^{\circ}C \leq T_{\text{amb}} \leq \text{+}105^{\circ}C$ 250 Long term input offset - voltage stability (1) 0.4 2 μV/Mo DVio Input offset voltage drift 0.5 1.8 µV/°C Input offset current ($V_{ic} = 0V$) 0.8 6 l_{io} nA $0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$ 7 Input offset current drift 50 pA/°C DIio 15 Input bias current drift 15 pA/°C DIib 50 Ro Open loop output resistance 60 Ω R_{id} Differential input resistance 33 MW 120 GW R_{ic} Common mode input resistance Input common mode voltage range ±13 ±13.5 V Vicm $0^{\circ}C \leq T_{\text{amb}} \leq \text{+}105^{\circ}C$ ±13 Common-mode rejection ratio (Vic = Vicm -min) 100 120 CMR dB $0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$ 97 Supply voltage rejection ratio ($V_{CC} = \pm 3$ to $\pm 18V$) 90 104 SVR dB $0^{\circ}C \leq T_{\text{amb}} \leq +105^{\circ}C$ 86 Large signal voltage gain $V_{CC} = \pm 15$, $R_L = 2k\Omega$, $V_0 = \pm 10V$ 120 400 V/mV A_{vd} $0^{\circ}C \leq T_{amb} \leq +105^{\circ}C$ 100 $V_{CC} = \pm 3$, $R_L = 500\Omega$, $V_O = \pm 0.5V$ 100 400 Output voltage swing $R_L = 10k\Omega$ ±12 ±13 V_{opp} V $R_L = 2k\Omega$ ±11.5 ±12.8 $R_L = 1k\Omega$ ±12 $0^{\circ}C \leq T_{amb} \leq +105^{\circ}C R_{L} = 2k\Omega$ ±11 SR Slew rate ($R_L = 2k\Omega$, $C_L = 100pF$) 0.17 V/µs GBP Gain bandwidth product ($R_1 = 2k\Omega$, $C_1 = 100pF$, f = 100kHz) 0.5 MHz 5 Supply current - no load 2.7 mΑ I_{CC} $0^{\circ}C \leq \, T_{amb} \leq \, \text{+}105^{\circ}C$ 6 $V_{CC} = \pm 3V$ 0.67 1.3 Equivalent input noise voltage f = 10Hz11 20 nV en f = 100Hz 10.5 13.5 _√Hz f = 1 kHz11.5 10 Equivalent input noise current f = 10Hz0.3 0.9 pА i_n f = 100Hz 0.2 0.3 √Hz f = 1 kHz0.1 0.2

Table 2. $V_{CC^+} = 15 \text{ V}, V_{CC^-} = \text{Ground}, T_{amb} = 25^{\circ} \text{ C} \text{ (unless otherwise specified)}$

Long term input offset voltage stability refers to the average trend line of Vio vs time over extended periods after the first 30 1. days of operation.



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